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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Preferred Device

Sensitive Gate Triacs

Silicon Bidirectional Thyristors

Designed primarily for full-wave AC control applications, such as light dimmers, motor controls, heating controls and power supplies; or wherever full-wave silicon gate controlled solid-state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied anode voltage with positive or negative gate triggering.

Features

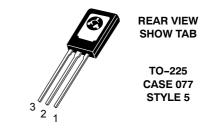
- Sensitive Gate Triggering Uniquely Compatible for Direct Coupling to TTL, HTL, CMOS and Operational Amplifier Integrated Circuit Logic Functions
- Gate Triggering: 4 Mode 2N6071A, B; 2N6073A, B; 2N6075A, B
- Blocking Voltages to 600 V
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermopad Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Device Marking: Device Type, e.g., 2N6071A, Date Code



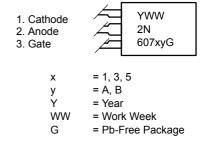
Littelfuse.com

TRIACS 4.0 A RMS, 200 - 600 V





MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
*Peak Repetitive Off-State Voltage (Note 1) (T _J = -40 to 110°C, Sine Wave, 50 to 60 Hz, Gate Open) 2N6071A,B 2N6073A,B 2N6075A,B	V _{DRM,} V _{RRM}	200 400 600	V
*On-State RMS Current (T _C = 85°C) Full Cycle Sine Wave 50 to 60 Hz	I _{T(RMS)}	4.0	Α
*Peak Non-repetitive Surge Current (One Full cycle, 60 Hz, T _J = +110°C)	I _{TSM}	30	Α
Circuit Fusing Considerations (t = 8.3 ms)	l ² t	3.7	A ² s
*Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 85°C)	P_{GM}	10	W
*Average Gate Power (t = 8.3 ms, T _C = 85°C)	P _{G(AV)}	0.5	W
*Peak Gate Voltage (Pulse Width ≤ 1.0 μs, T _C = 85°C)	V _{GM}	5.0	V
*Operating Junction Temperature Range	TJ	-40 to +110	°C
*Storage Temperature Range	T _{stg}	-40 to +150	°C
Mounting Torque (6-32 Screw) (Note 2)	-	8.0	in. lb.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
*Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	3.5	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{ heta JA}$	75	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

^{*}Indicates JEDEC Registered Data.

^{1.} V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

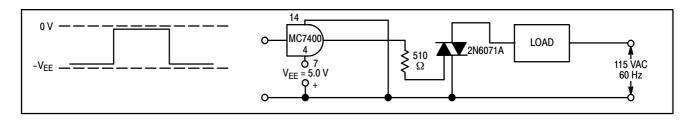
^{2.} Torque rating applies with use of a compression washer. Mounting torque in excess of 6 in. lb. does not appreciably lower case-to-sink thermal resistance. Main terminal 2 and heatsink contact pad are common.

$\textbf{ELECTRICAL CHARACTERISTICS} \ (T_{C} = 25^{\circ}\text{C unless otherwise noted}; \ \text{Electricals apply in both directions})$

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
*Peak Repetitive Blocking Current $(V_D = V_{DRM} = V_{RRM}; Gate Open)$ $T_J = 25$ $T_J = 11$		I _{DRM,} I _{RRM}	- -		10 2	μA mA
ON CHARACTERISTICS						
*Peak On-State Voltage (Note 3) (I _{TM} = ±6.0 A Peak)		V_{TM}	-	-	2	V
*Gate Trigger Voltage (Continuous DC), All Quadrants (Main Terminal Voltage = 12 Vdc, R_L = 100 Ω , T_J = -40 °C)	V _{GT}	-	1.4	2.5	V	
Gate Non- Trigger Voltage, All Quadrants V_{GD} (Main Terminal Voltage = 12 Vdc, R_L = 100 Ω , T_J = 110°C)				-	-	V
*Holding Current (Main Terminal Voltage = 12 Vdc, Gate Open, Initiating Current = \pm 1 T $_{J}$ = -4 T $_{J}$ = 25	.0 °C [′]	I _H			30 15	mA
Turn-On Time (I _{TM} = 14 Adc, I _{GT} = 100 mAdc)		t _{gt}	-	1.5	-	μS
			(QUAD Maximu	RANT m Value)
	Туре	I _{GT} @ T _J	I mA	II mA	III mA	IV mA
Gate Trigger Current (Continuous DC)	2N6071A	+25°C	5	5	5	10
(Main Terminal Voltage = 12 Vdc, R_L = 100 Ω)	2N6073A 2N6075A	-40 °C	20	20	20	30
	2N6071B 2N6073B	+25°C	3	3	3	5
	2N6075B	-40 °C	15	15	15	20
DYNAMIC CHARACTERISTICS						
Critical Rate of Rise of Commutation Voltage @ V _{DRM} , T _J = 85°C, Gate Open, I _{TM} = 5.7 A, Exponential Waveform Commutating di/dt = 2.0 A/ms	١,	dv/dt(c)	-	5	-	V/μs

^{3.} Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

SAMPLE APPLICATION: TTL-SENSITIVE GATE 4 AMPERE TRIAC TRIGGERS IN MODES II AND III



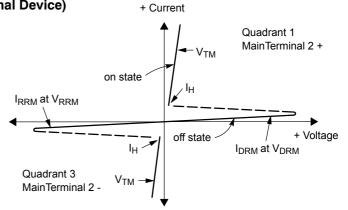
Trigger devices are recommended for gating on Triacs. They provide:

- 1. Consistent predictable turn-on points.
- 2. Simplified circuitry.
- 3. Fast turn-on time for cooler, more efficient and reliable operation.

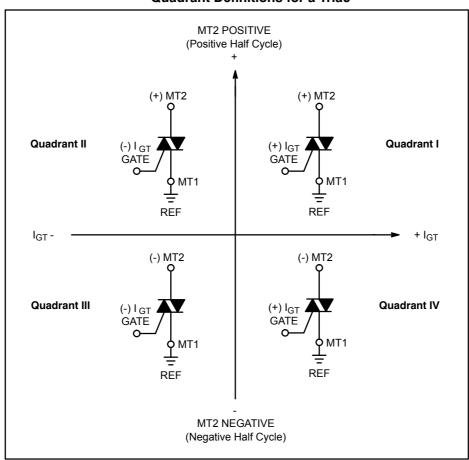
^{*}Indicates JEDEC Registered Data.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V _{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V _{TM}	Maximum On State Voltage
I _H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

SENSITIVE GATE LOGIC REFERENCE

IC Logic Functions	Firing Quadrant			
ic Logic Functions	1	II	III	IV
TTL		2N6071A Series	2N6071A Series	
HTL		2N6071A Series	2N6071A Series	
CMOS (NAND)	2N6071B Series			2N6071B Series
CMOS (Buffer)		2N6071B Series	2N6071B Series	
Operational Amplifier	2N6071A Series			2N6071A Series
Zero Voltage Switch		2N6071A Series	2N6071A Series	

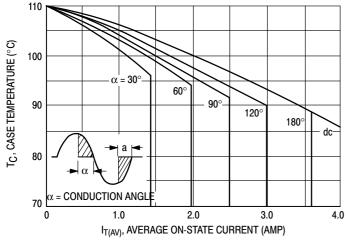


Figure 1. Average Current Derating

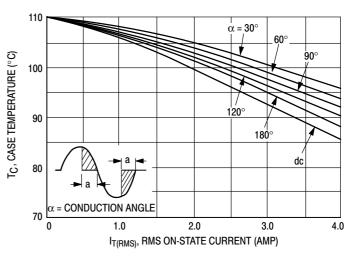


Figure 2. RMS Current Derating

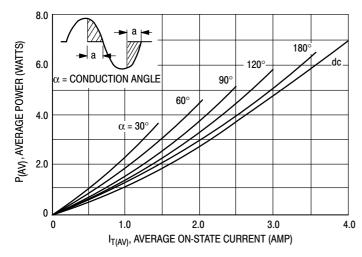


Figure 3. Power Dissipation

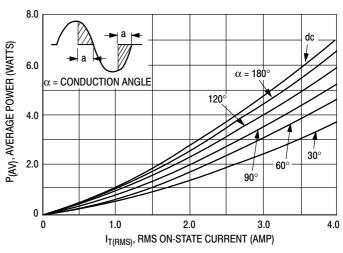


Figure 4. Power Dissipation

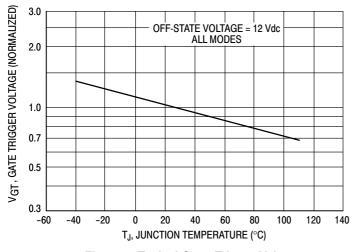


Figure 5. Typical Gate-Trigger Voltage

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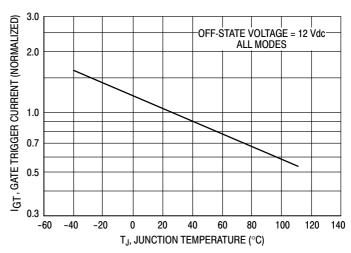


Figure 6. Typical Gate-Trigger Current

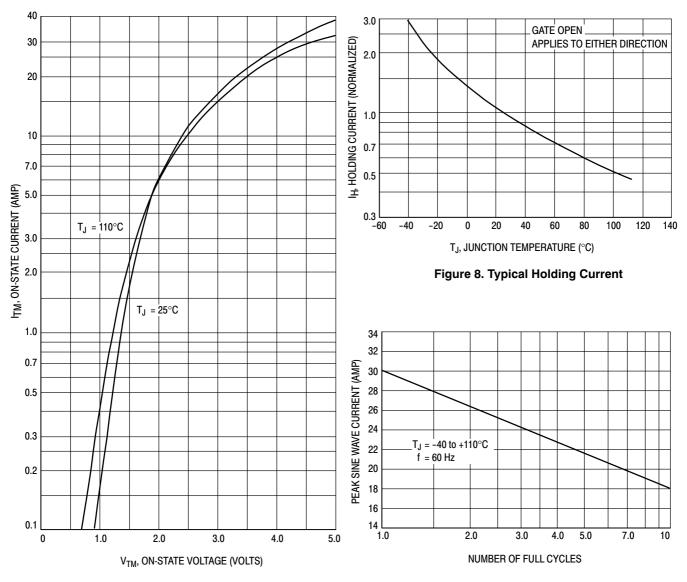


Figure 7. Maximum On-State Characteristics

Figure 9. Maximum Allowable Surge Current

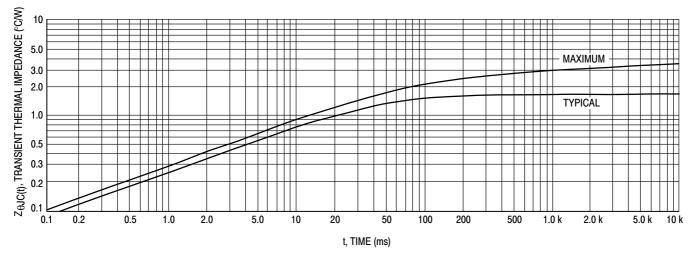


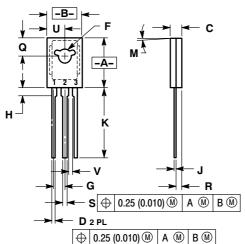
Figure 10. Thermal Response

ORDERING INFORMATION

Device	Package	Shipping [†]			
2N6071A	TO-225				
2N6071AG	TO-225 (Pb-Free)	500 Units / Box			
2N6071AT	TO-225	50 Units / Tube 2000 Units / Box			
2N6071ATG	TO-225 (Pb-Free)	50 Units / Tube 2000 Units / Box			
2N6071B	TO-225				
2N6071BG	TO-225 (Pb-Free)	500 Units / Box			
2N6071BT	TO-225	50 Units / Tube 2000 Units / Box			
2N6071BTG	TO-225 (Pb-Free)	50 Units / Tube 2000 Units / Box			
2N6073A	TO-225				
2N6073AG	TO-225 (Pb-Free)				
2N6073B	TO-225	7			
2N6073BG	TO-225 (Pb-Free)				
2N6075A	TO-225	500 Units / Box			
2N6075AG	TO-225 (Pb-Free)	1			
2N6075B	TO-225	1			
2N6075BG	TO-225 (Pb-Free)				

PACKAGE DIMENSIONS

TO-225 CASE 77-09 **ISSUE Z**



- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
 3. 077-01 THRU -08 OBSOLETE, NEW STANDARD

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.425	0.435	10.80	11.04
В	0.295	0.305	7.50	7.74
С	0.095	0.105	2.42	2.66
D	0.020	0.026	0.51	0.66
F	0.115	0.130	2.93	3.30
G	0.094 BSC		2.39 BSC	
Н	0.050	0.095	1.27	2.41
J	0.015	0.025	0.39	0.63
K	0.575	0.655	14.61	16.63
M	5° TYP		5° TYP	
Q	0.148	0.158	3.76	4.01
R	0.045	0.065	1.15	1.65
S	0.025	0.035	0.64	0.88
U	0.145	0.155	3.69	3.93
٧	0.040		1.02	

STYLE 5: PIN 1. MT 1

MT 2

GATE

Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse.

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